

HD74LS136

Quadruple 2-Input Exclusive-OR Gates (with open collector outputs)

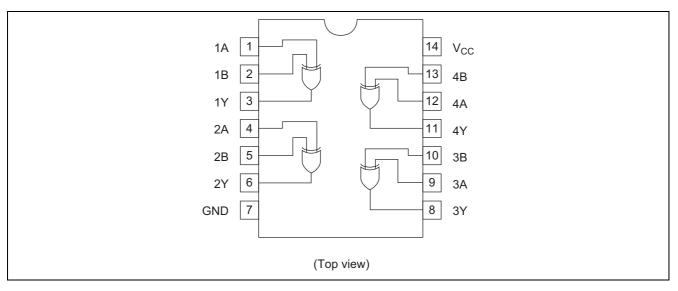
REJ03D0433-0300 Rev.3.00 Jul.13.2005

Features

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74LS136FPEL	SOP-14 pin (JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)	

Pin Arrangement



Function Table

Inp	Output		
A	В	Y	
L	L	L	
L	Н	Н	
Н	L	Н	
Н	Н	L	

Note: H; high level,

L; low level,

X ; irrelevant.



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	7	V	
Input voltage	V _{IN}	7	V	
Power dissipation	PT	400	mW	
Storage temperature	Tstg	-65 to +150	°C	

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

Recommended Operating Conditions

ltem	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{CC}	4.75	5.00	5.25	V
High level output voltage	V _{OH}	—	—	5.5	V
Low level output current	I _{OL}	—	—	8	mA
Operating temperature	Topr	-20	25	75	°C

Electrical Characteristics

 $(Ta = -20 \text{ to } +75 \ ^{\circ}\text{C})$

Item	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	V _{IH}	2.0		_	V	
input voltage	VIL	_		0.8	V	
Output current	I _{OH}	_		100	μA	
Output voltage	V _{OL}	_		0.4	V	$I_{OL} = 4 \text{ mA}$ $V_{CC} = 4.75 \text{ V}, V_{IH} = 2 \text{ V},$
Output voltage		—	-	0.5	v	$I_{OL} = 8 \text{ mA}$ $V_{IL} = 0.8 \text{ V},$
	I _{IH}	—	-	40	μΑ	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 2.7 \text{ V}$
Input current	IIL	—	-	-0.8	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 0.4 \text{ V}$
	I _I	—	-	0.2	mA	$V_{CC} = 5.25 \text{ V}, \text{ V}_{I} = 7 \text{ V}$
Supply current**	I _{CC}	—	6.1	10	mA	V _{CC} = 5.25 V
Input clamp voltage	V _{IR}	_		-1.5	V	$V_{CC} = 4.75 \text{ V}, \text{ I}_{IN} = -18 \text{ mA}$

Notes: * $V_{CC} = 5 V$, Ta = 25°C

** I_{CC} is measured with one input of each gate at 4.5 V, the other inputs grounded, and the outputs open.

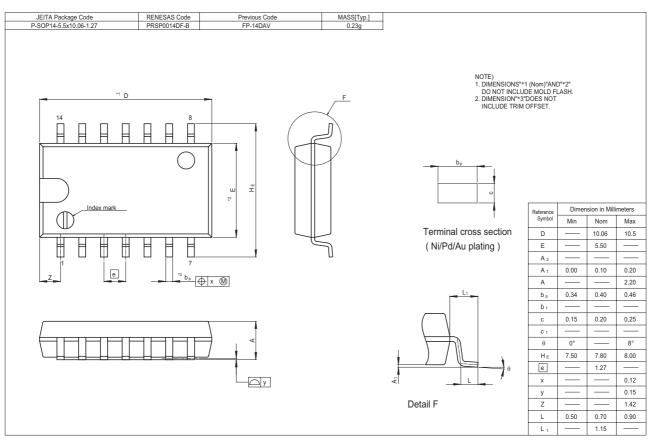
Switching Characteristics

 $(V_{CC} = 5 V, Ta = 25^{\circ}C)$

ltem	Symbol	min.	typ.	max.	Unit	Inputs	Condition	
Propagation delay time	t _{PLH}	_	18	30	ns	A or B	Other	C _L = 15 pF,
	t _{PHL}	—	18	30			inputs "L"	
	t _{PLH}	—	18	30	ns	A or B	Other	$R_L = 2 k\Omega$
	t _{PLH}	—	18	30			inputs "H"	

Note: Refer to Test Circuit and Waveform of the Common Item "TTL Common Matter (Document No.: REJ27D0005-0100)".

Package Dimensions





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